imall

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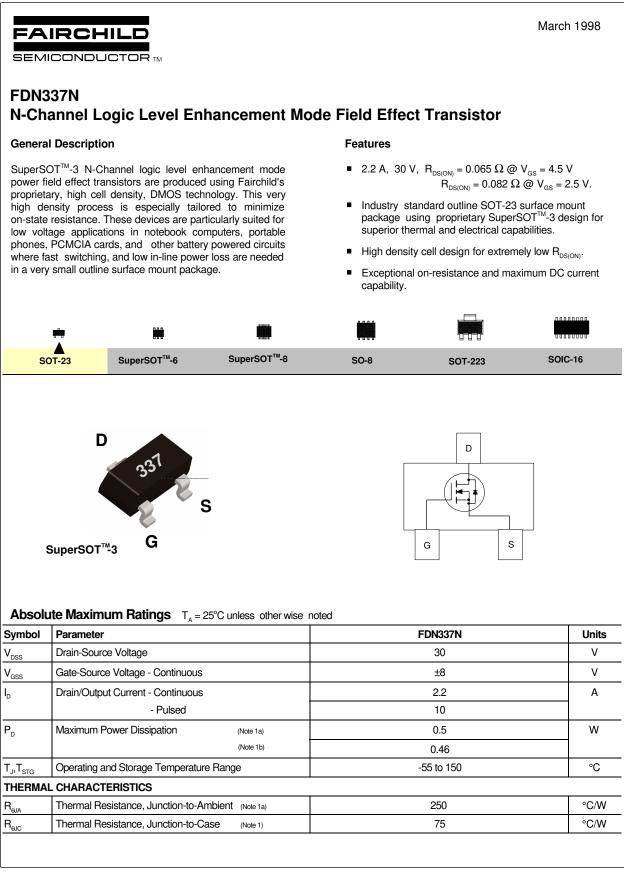
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Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAF	ACTERISTICS					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{\rm GS} = 0 V, \ I_{\rm D} = 250 \ \mu A$	30			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	I_{D} = 250 µA, Referenced to 25 °C		41		mV/ °C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ $T_{J} = 55^{\circ}\text{C}$			1	μA
					10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
	Gate - Body Leakage, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
ON CHARA	CTERISTICS (Note)					
V _{GS(th)}	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}, \ I_{\text{D}} = 250 \ \mu\text{A}$	0.4	0.7	1	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	I_{D} = 250 µA, Referenced to 25 °C		-2.3		mV/ °C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = 4.5 \text{ V}, \ I_{D} = 2.2 \text{ A}$		0.054	0.065	Ω
		T _J =125°C		0.08	0.11	
		$V_{\rm GS} = 2.5 \text{ V}, \ I_{\rm D} = 2 \text{ A}$		0.07	0.082	
D(ON)	On-State Drain Current	$V_{GS} = 4.5 \text{ V}, V_{DS} = 5 \text{ V}$	10			Α
9 _{FS}	Forward Transconductance	$V_{\rm DS} = 5 \text{ V}, \ I_{\rm D} = 2.2 \text{ A}$		13		S
DYNAMIC	CHARACTERISTICS					
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, $ f = 1.0 MHz		300		pF
C _{oss}	Output Capacitance			145		pF
C _{rss}	Reverse Transfer Capacitance			35		pF
SWITCHIN	G CHARACTERISTICS (Note)					
t _{D(on)}	Turn - On Delay Time	$V_{DD} = 5 V, I_{D} = 1 A,$		4	10	ns
ţ	Turn - On Rise Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		10	18	ns
D(off)	Turn - Off Delay Time			17	28	ns
t _r	Turn - Off Fall Time			4	10	ns
Q	Total Gate Charge	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 2.2 \text{ A},$ $V_{GS} = 4.5 \text{ V}$		7	9	nC
Q_{gs}	Gate-Source Charge			1.1		nC
Q _{gd}	Gate-Drain Charge			1.9		nC
DRAIN-SO	URCE DIODE CHARACTERISTICS AND M	AXIMUM RATINGS				
s	Maximum Continuous Drain-Source Diode Fo	Source Diode Forward Current			0.42	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{\rm GS} = 0 \ V, \ I_{\rm S} = 0.42 \ A \ {\rm (Note)}$		0.65	1.2	V

1. R_{BA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BAC} is guaranteed by design while R_{BAC} is determined by the user's board design.

Typical $\rm R_{\rm BM}$ using the board layouts shown below on FR-4 PCB in a still air environment :

а

Scale 1 : 1 on letter size paper

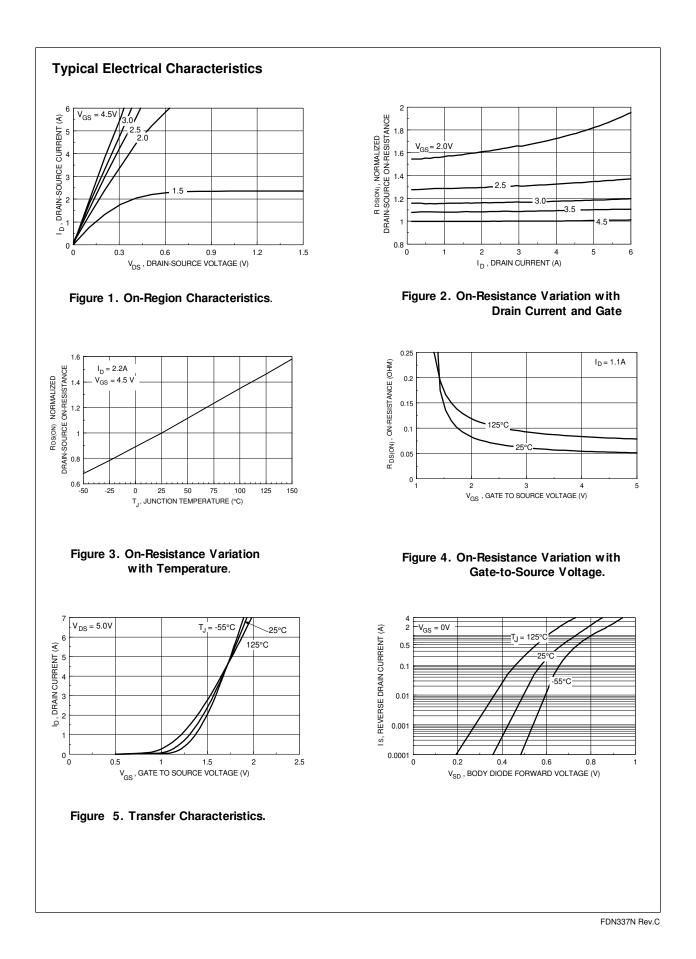
2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.

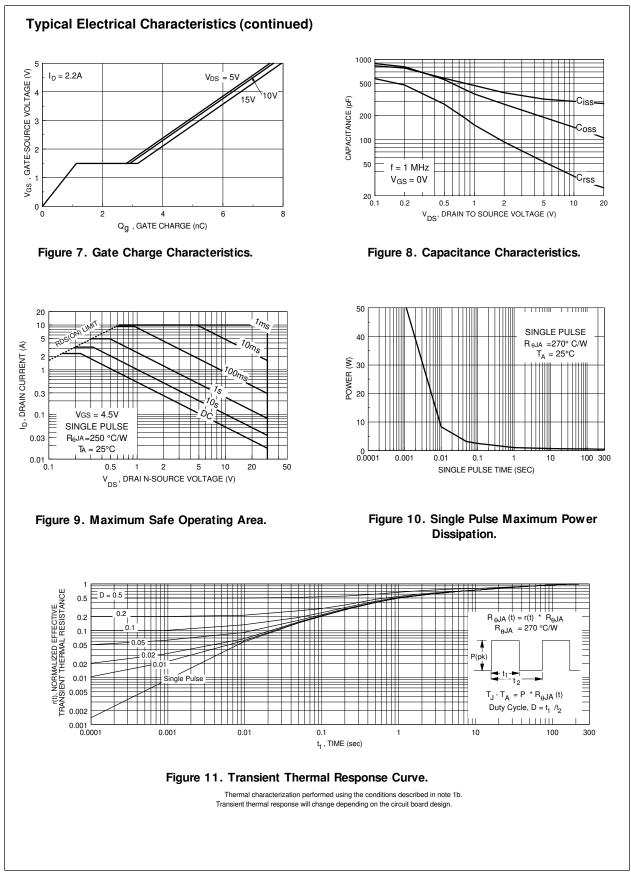


a. 250°C/W when mounted on 0.02 in² pad of 2oz Cu.

1 .\\

b. 270°C/W when mounted on a 0.001 in² pad of 2oz Cu.





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